

SS9015

Low Frequency, Low Noise Amplifier

Complement to SS9014



1. Emitter 2. Base 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	-50	V
V _{CEO}	Collector-Emitter Voltage	-45	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-100	mA
P _C	Collector Power Dissipation	450	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = -100 \mu A, I_E = 0$	-50			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = -1mA, I _B =0	-45			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -100 \mu A, I_C = 0$	-5			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = -50V, I_{E} = 0$			-50	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$			-50	nA
h _{FE}	DC Current Gain	$V_{CE} = -5V, I_{C} = -1mA$	60		1000	
V _{CE} (sat)	Collector-Base Saturation Voltage	$I_C = -100 \text{mA}, I_B = -5 \text{mA}$			-0.7	
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = -100 \text{mA}, I_B = -5 \text{mA}$			-1.0	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = -5V, I_{C} = -2mA$	-0.6		-0.75	V
C _{ob}	Output Capacitance	V _{CB} = -10V, I _E =0 f=1MHz		4.5	7.0	pF
f _T	Current Gain Bandwidth Product	$V_{CE} = -5V, I_{C} = -10mA$	100	190		MHz
NF	Noise Figure	V_{CE} = -5V, I_{C} = -0.2mA f=1KHz, R_{S} =1K Ω		0.7	10	dB

h_{FE} Classification

Classification	A	В	С	D
h _{FE}	60 ~ 150	100 ~ 300	200 ~ 600	400 ~ 1000

Typical Characteristics

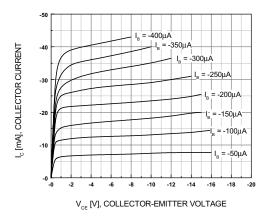


Figure 1. Static Characteristic

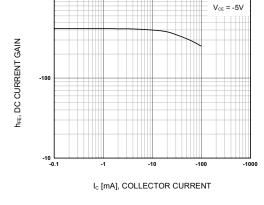


Figure 2. DC current Gain

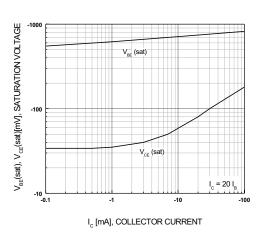


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

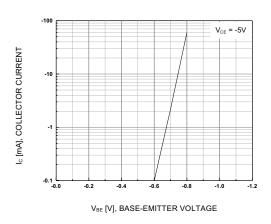


Figure 4. Base-Emitter On Voltage

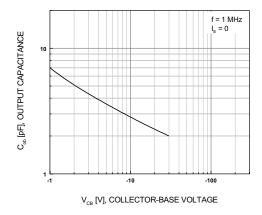


Figure 5. Collector Output Capacitance

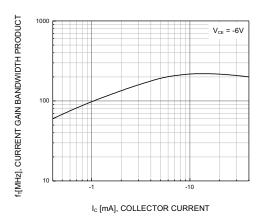
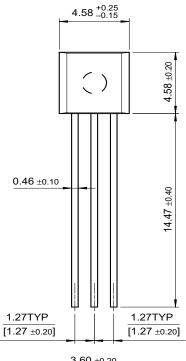


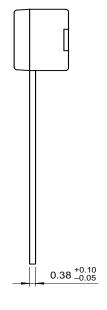
Figure 6. Current Gian Bandwidth Product

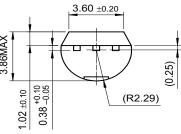
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Package Dimensions

TO-92







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Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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